

MC74VHC259

8-Bit Addressable Latch/1-of-8 Decoder CMOS Logic Level Shifter with LSTTL-Compatible Inputs

The MC74VHC259 is an 8-bit Addressable Latch fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL devices while maintaining CMOS low power dissipation.

The VHC259 is designed for general purpose storage applications in digital systems. The device has four modes of operation as shown in the mode selection table. In the addressable latch mode, the data on Data In is written into the addressed latch. The addressed latch follows the data input with all non-addressed latches remaining in their previous states. In the memory mode, all latches remain in their previous state and are unaffected by the Data or Address inputs. In the one-of-eight decoding or demultiplexing mode, the addressed output follows the state of Data In with all other outputs in the LOW state. In the Reset mode, all outputs are LOW and unaffected by the address and data inputs. When operating the VHC259 as an addressable latch, changing more than one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode.

The MC74VHC259 input structure provides protection when voltages up to 7 V are applied, regardless of the supply voltage. This allows the MC74VHC259 to be used to interface 5 V circuits to 3 V circuits.

- High Speed: $t_{PD} = 7.6 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation: $I_{CC} = 2 \mu\text{A}$ (Max) at $T_A = 25^\circ\text{C}$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- CMOS-Compatible Outputs: $V_{OH} > 0.8 V_{CC}$; $V_{OL} < 0.1 V_{CC} @\text{Load}$
- Power Down Protection Provided on Inputs and Outputs
- Balanced Propagation Delays
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: HBM > 2000 V
- These Devices are Pb-Free and are RoHS Compliant

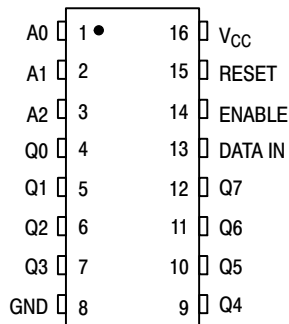


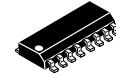
Figure 1. Pin Assignment



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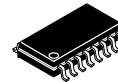
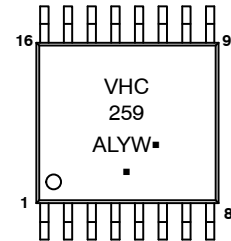
MARKING DIAGRAMS



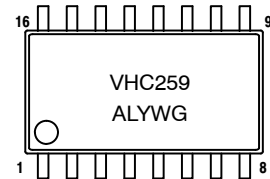
SOIC-16
D SUFFIX
CASE 751B



TSSOP-16
DT SUFFIX
CASE 948F



SOIC EIAJ-16
M SUFFIX
CASE 966



A = Assembly Location
L, WL = Wafer Lot
Y, YY = Year
W, WW = Work Week
G or ■ = Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping |
|-----------------|--------------|-----------------|
| MC74VHC259DG | SOIC-16 | 48 Units/Rail |
| MC74VHC259DR2G | SOIC-16 | 2500 Units/Reel |
| MC74VHC259DTG | TSSOP-16 | 96 Units/Rail |
| MC74VHC259DTR2G | TSSOP-16 | 2500 Units/Reel |
| MC74VHC259MG | SOIC EIAJ-16 | 50 Units/Rail |

MC74VHC259

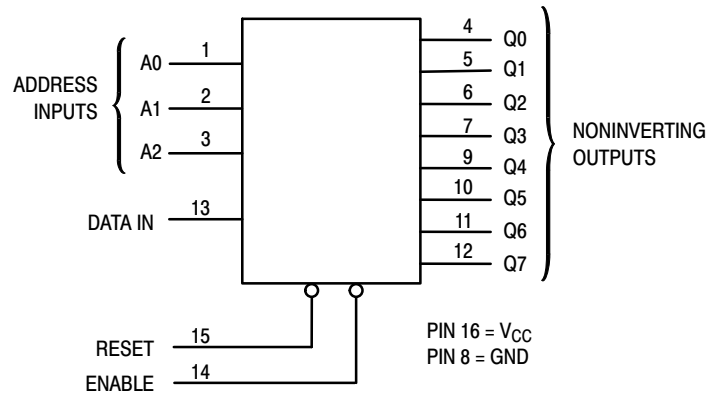


Figure 2. Logic Diagram

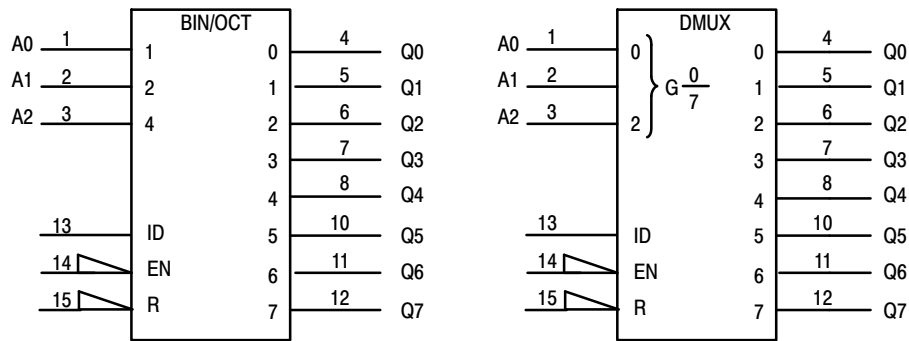


Figure 3. IEC Logic Symbol

LATCH SELECTION TABLE

| Address Inputs | | | Latch Addressed |
|----------------|---|---|-----------------|
| C | B | A | |
| L | L | L | Q0 |
| L | L | H | Q1 |
| L | H | L | Q2 |
| L | H | H | Q3 |
| H | L | L | Q4 |
| H | L | H | Q5 |
| H | H | L | Q6 |
| H | H | H | Q7 |

MODE SELECTION TABLE

| Enable | Reset | Mode |
|--------|-------|----------------------|
| L | H | Addressable Latch |
| H | H | Memory |
| L | L | 8-Line Demultiplexer |
| H | L | Reset |

MC74VHC259

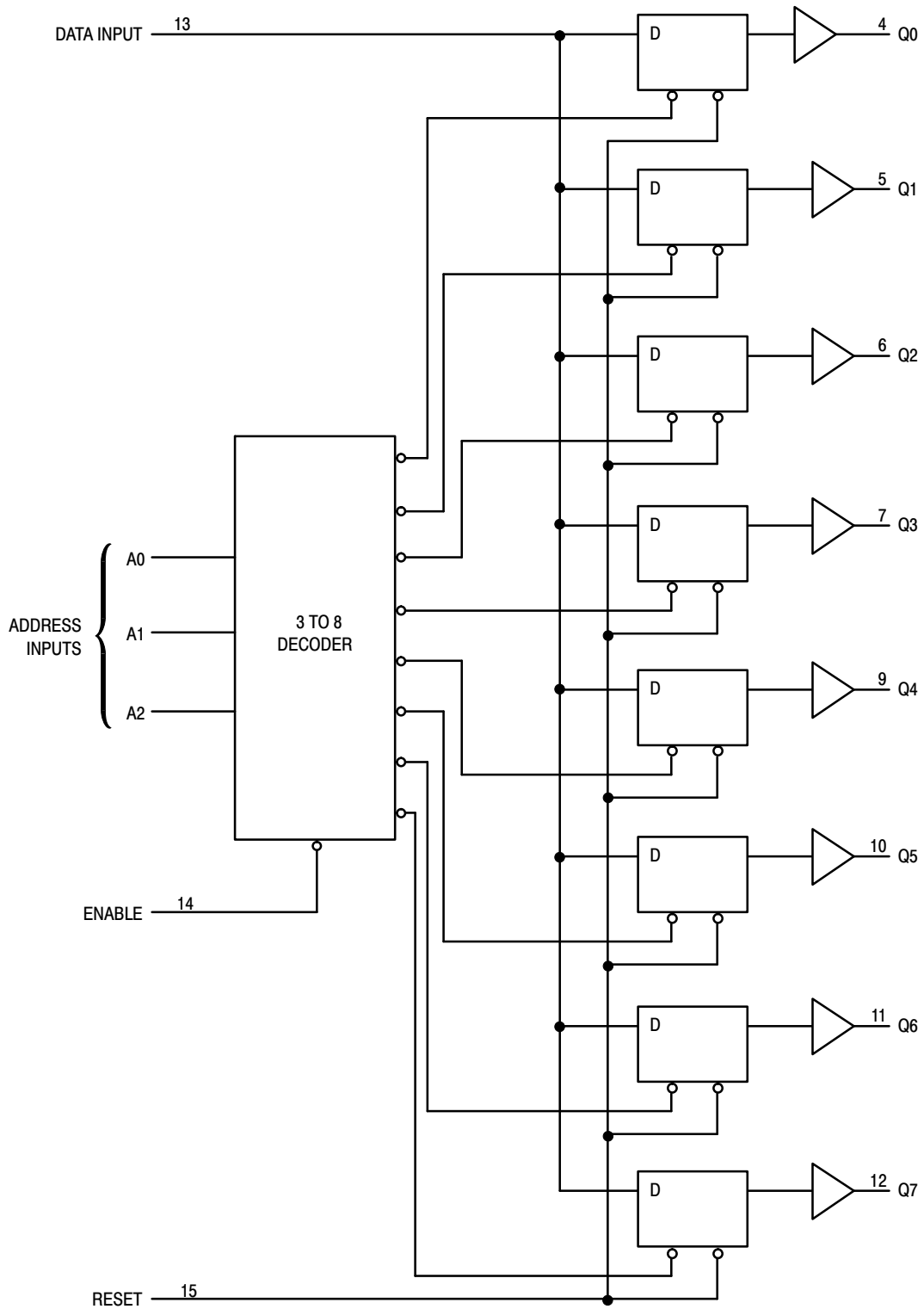


Figure 4. Expanded Logic Diagram

MC74VHC259

MAXIMUM RATINGS (Note 1.)

| Symbol | Parameter | Value | Unit | |
|-----------------------|---|---|------------------------|------|
| V _{CC} | Positive DC Supply Voltage | -0.5 to +7.0 | V | |
| V _{IN} | Digital Input Voltage | -0.5 to +7.0 | V | |
| V _{OUT} | DC Output Voltage | -0.5 to V _{CC} +0.5 | V | |
| I _{IK} | Input Diode Current | -20 | mA | |
| I _{OK} | Output Diode Current | ± 20 | mA | |
| I _{OUT} | DC Output Current, per Pin | ± 25 | mA | |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ± 75 | mA | |
| P _D | Power Dissipation in Still Air | SOIC Package TSSOP | 200 180 | mW |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C | |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 2.) Machine Model (Note 3.) Charged Device Model (Note 4.) | >2000 >200 >2000 | V |
| I _{LATCH-UP} | Latch-Up Performance | Above V _{CC} and Below GND at 125°C (Note 5.) | ± 300 | mA |
| θ _{JA} | Thermal Resistance, Junction to Ambient | SOIC Package TSSOP | 143 164 | °C/W |

1. Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.
2. Tested to EIA/JESD22-A114-A
3. Tested to EIA/JESD22-A115-A
4. Tested to JESD22-C101-A
5. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

| Symbol | Characteristics | Min | Max | Unit |
|---------------------------------|--|-----|--|------|
| V _{CC} | DC Supply Voltage | 2.0 | 5.5 | V |
| V _{IN} | DC Input Voltage | 0 | 5.5 | V |
| V _{OUT} | DC Output Voltage | 0 | V _{CC} | V |
| T _A | Operating Temperature Range, all Package Types | -55 | 125 | °C |
| t _r , t _f | Input Rise or Fall Time | | | ns/V |
| | | | V _{CC} = 3.3 V ± 0.3 V V _{CC} = 5.0 V ± 0.5 V | |

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction Temperature °C | Time, Hours | Time, Years |
|-------------------------|-------------|-------------|
| 80 | 1,032,200 | 117.8 |
| 90 | 419,300 | 47.9 |
| 100 | 178,700 | 20.4 |
| 110 | 79,600 | 9.4 |
| 120 | 37,000 | 4.2 |
| 130 | 17,800 | 2.0 |
| 140 | 8,900 | 1.0 |

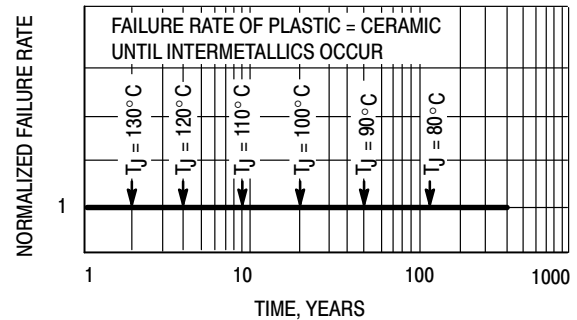


Figure 5. Failure Rate vs. Time Junction Temperature

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DC CHARACTERISTICS (Voltages Referenced to GND)

| Symbol | Parameter | Condition | V _{CC} (V) | T _A = 25°C | | | -55°C ≤ T _A ≤ 125°C | | Unit |
|-----------------|-----------------------------------|--|------------------------|-----------------------------|-------------------|-----------------------------|--------------------------------|-----------------------------|------|
| | | | | Min | Typ | Max | Min | Max | |
| V _{IH} | Minimum High-Level Input Voltage | | 2.0 3.0 to 5.5 | 1.5 V _{CCX} 0.7 | | | 1.5 V _{CCX} 0.7 | | V |
| V _{IL} | Maximum Low-Level Input Voltage | | 2.0 3.0 to 5.5 | | | 0.5 V _{CCX} 0.3 | | 0.5 V _{CCX} 0.3 | V |
| V _{OH} | Maximum High-Level Output Voltage | V _{IN} = V _{IH} or V _{IL} I _{OH} = -50 μA | 2.0 3.0 4.5 | 1.9 2.9 4.4 | 2.0 3.0 4.5 | | 1.9 2.9 4.4 | | V |
| | | V _{IN} = V _{IH} or V _{IL} I _{OL} = 4 mA I _{OL} = 8 mA | 3.0 4.5 | 2.58 3.94 | | | 2.48 3.8 | | V |
| V _{OL} | Maximum Low-Level Output Voltage | V _{IN} = V _{IH} or V _{IL} I _{OL} = 50 μA | 2.0 3.0 4.5 | | 0.0 0.0 0.0 | 0.1 0.1 0.1 | | 0.1 0.1 0.1 | V |
| | | V _{IN} = V _{IH} or V _{IL} I _{OL} = 4 mA I _{OL} = 8 mA | 3.0 4.5 | | 0.36 0.36 | | | 0.44 0.44 | V |
| I _{IN} | Input Leakage Current | V _{IN} = 5.5 V or GND | 0 to 5.5 | | | ±0.1 | | ±1.0 | μA |
| I _{CC} | Maximum Quiescent Supply Current | V _{IN} = V _{CC} or GND | 5.5 | | | 4.0 | | 40.0 | μA |

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3.0ns)

| Symbol | Parameter | Test Conditions | T _A = 25°C | | | T _A ≤ 85°C | | -55°C ≤ T _A ≤ 125°C | | Unit |
|--|--|---|-----------------------|------------|-------------|-----------------------|--------------|--------------------------------|--------------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Data to Output (Figures 6 and 11) | V _{CC} = 3.3 ± 0.3V C _L = 15pF C _L = 50pF | | 6.0 8.5 | 8.5 12.5 | 1.0 1.0 | 11.5 14.5 | 1.0 1.0 | 11.5 14.5 | ns |
| | | V _{CC} = 5.0 ± 0.5V C _L = 15pF C _L = 50pF | | 4.9 7.0 | 8.0 10.0 | 1.0 1.0 | 9.5 11.5 | 1.0 1.0 | 9.5 11.5 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Address Select to Output (Figures 7 and 11) | V _{CC} = 3.3 ± 0.3V C _L = 15pF C _L = 50pF | | 6.0 8.5 | 8.5 12.5 | 1.0 1.0 | 11.5 14.5 | 1.0 1.0 | 11.5 14.5 | ns |
| | | V _{CC} = 5.0 ± 0.5V C _L = 15pF C _L = 50pF | | 4.9 7.0 | 8.0 10.0 | 1.0 1.0 | 9.5 11.5 | 1.0 1.0 | 9.5 11.5 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Enable to Output (Figures 8 and 11) | V _{CC} = 3.3 ± 0.3V C _L = 15pF C _L = 50pF | | 6.0 8.5 | 8.5 12.5 | 1.0 1.0 | 11.5 14.5 | 1.0 1.0 | 11.5 14.5 | ns |
| | | V _{CC} = 5.0 ± 0.5V C _L = 15pF C _L = 50pF | | 4.9 7.0 | 8.0 10.0 | 1.0 1.0 | 9.5 11.5 | 1.0 1.0 | 9.5 11.5 | |
| t _{PHL} | Maximum Propagation Delay, Reset to Output (Figures 9 and 11) | V _{CC} = 3.3 ± 0.3V C _L = 15pF C _L = 50pF | | 6.0 8.5 | 8.5 12.5 | 1.0 1.0 | 11.5 14.5 | 1.0 1.0 | 11.5 14.5 | ns |
| | | V _{CC} = 5.0 ± 0.5V C _L = 15pF C _L = 50pF | | 4.9 7.0 | 8.0 10.0 | 1.0 1.0 | 9.5 11.5 | 1.0 1.0 | 9.5 11.5 | |
| C _{IN} | Maximum Input Capacitance | | | 6 10 | 10 | | 10 | | 10 | pF |

| C _{PD} | Power Dissipation Capacitance (Note 1) | Typical @ 25°C, V _{CC} = 5.0V | | pF |
|-----------------|--|--|--|----|
| | | 30 | | |
| | | | | |

1. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

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TIMING REQUIREMENTS (Input $t_r = t_f = 3.0\text{ns}$)

| Symbol | Parameter | Test Conditions | $T_A = 25^\circ\text{C}$ | | | $T_A \leq 85^\circ\text{C}$ | | $T_A \leq 125^\circ\text{C}$ | | Unit |
|------------|--|--------------------------------|--------------------------|-----|-----|-----------------------------|-----|------------------------------|-----|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_w | Minimum Pulse Width, Reset or Enable (Figure 10) | $V_{CC} = 3.3 \pm 0.3\text{V}$ | 5.0 | | | 5.5 | | 5.5 | | ns |
| | | $V_{CC} = 5.0 \pm 0.5\text{V}$ | 5.0 | | | 5.5 | | 5.5 | | |
| t_{su} | Minimum Setup Time, Address or Data to Enable (Figure 10) | $V_{CC} = 3.3 \pm 0.3\text{V}$ | 4.5 | | | 4.5 | | 4.5 | | ns |
| | | $V_{CC} = 5.0 \pm 0.5\text{V}$ | 3.0 | | | 3.0 | | 3.0 | | |
| t_h | Minimum Hold Time, Enable to Address or Data (Figure 8 or 9) | $V_{CC} = 3.3 \pm 0.3\text{V}$ | 2.0 | | | 2.0 | | 2.0 | | ns |
| | | $V_{CC} = 5.0 \pm 0.5\text{V}$ | 2.0 | | | 2.0 | | 2.0 | | |
| t_r, t_f | Maximum Input, Rise and Fall Times (Figure 6) | $V_{CC} = 3.3 \pm 0.3\text{V}$ | | | 400 | | 300 | | 300 | ns |
| | | $V_{CC} = 5.0 \pm 0.5\text{V}$ | | | 200 | | 100 | | 100 | |

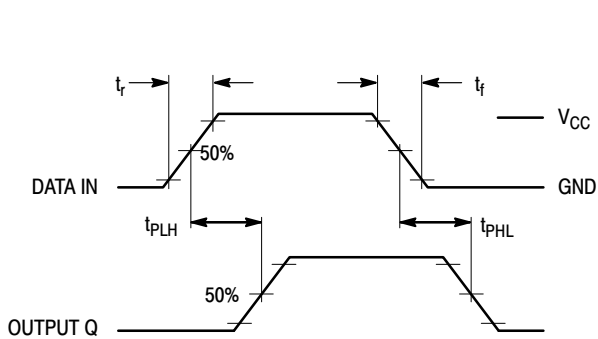


Figure 6. Switching Waveform

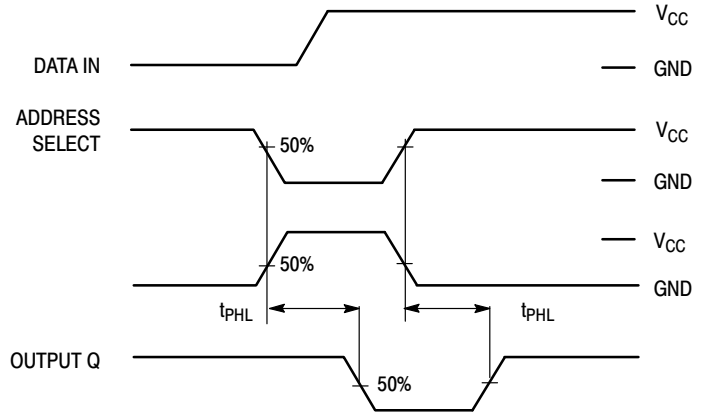


Figure 7. Switching Waveform

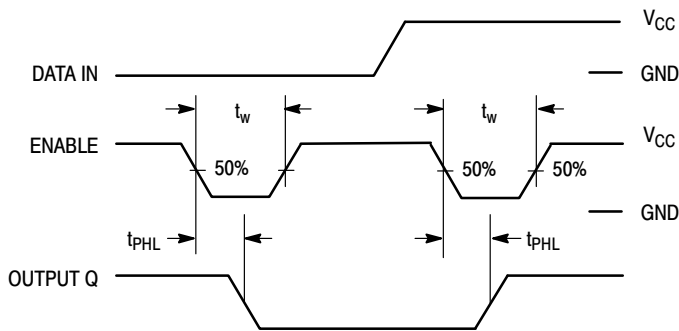


Figure 8. Switching Waveform

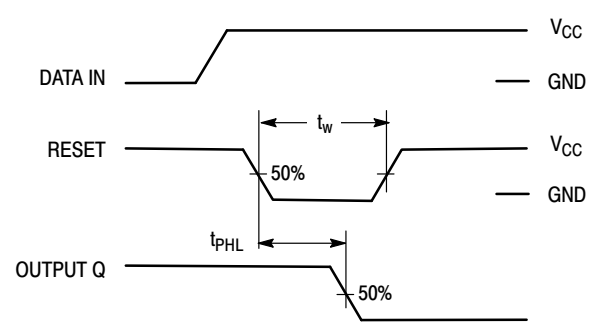


Figure 9. Switching Waveform

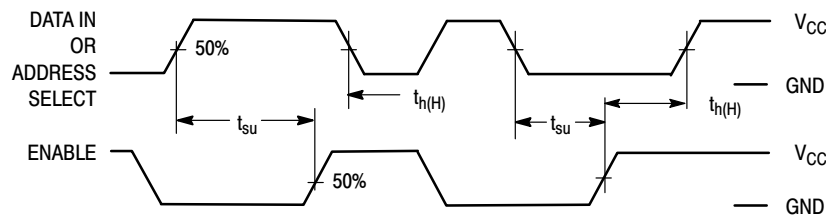
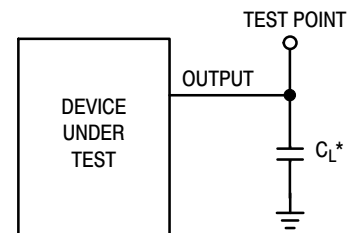


Figure 10. Switching Waveform



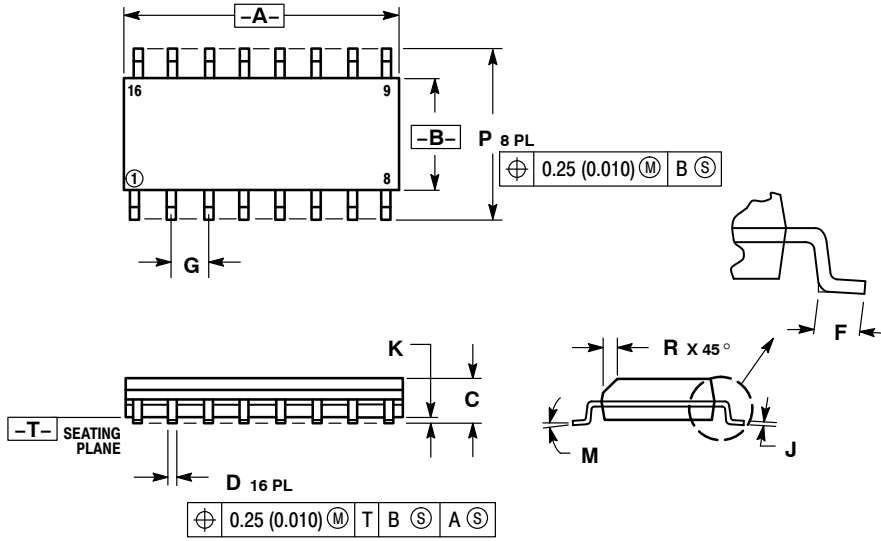
*Includes all probe and jig capacitance

Figure 11. Test Circuit

MC74VHC259

PACKAGE DIMENSIONS

SOIC-16
CASE 751B-05
ISSUE K

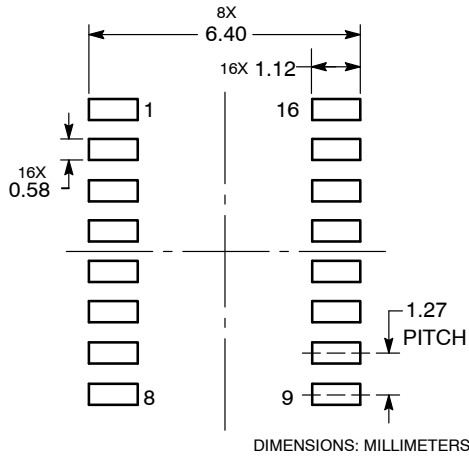


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 9.80 | 10.00 | 0.386 | 0.393 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 BSC | | 0.050 BSC | |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0° | 7° | 0° | 7° |
| P | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

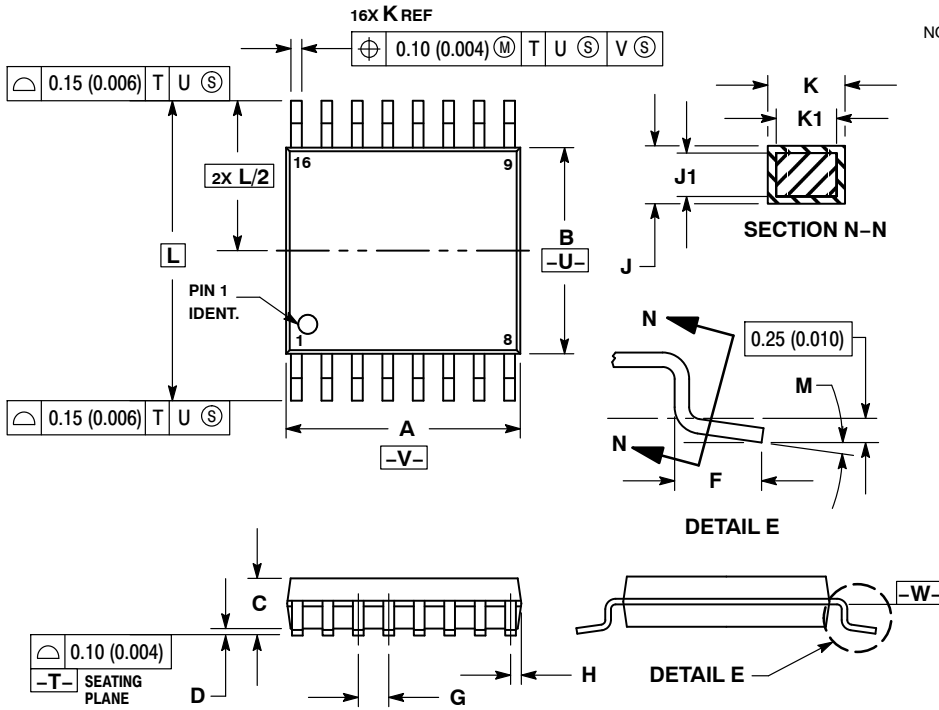
SOLDERING FOOTPRINT



MC74VHC259

PACKAGE DIMENSIONS

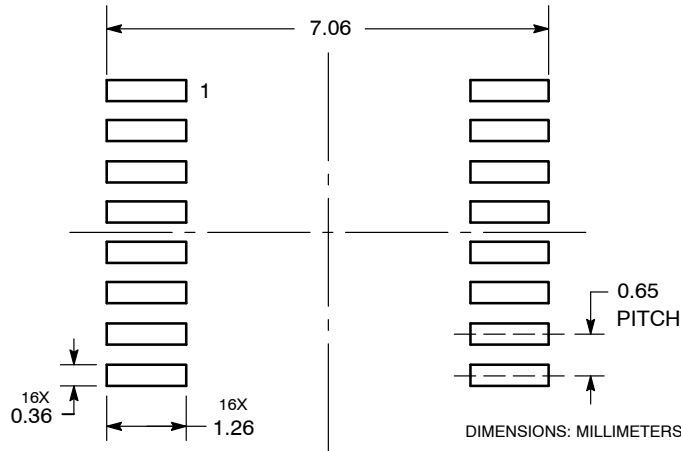
TSSOP-16
CASE 948F-01
ISSUE B



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

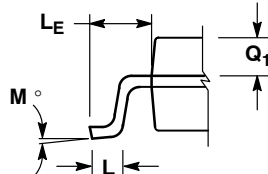
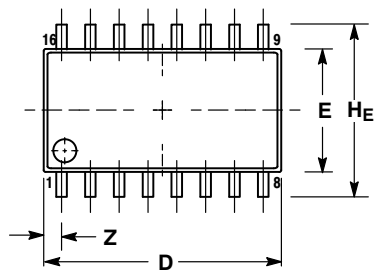
SOLDERING FOOTPRINT



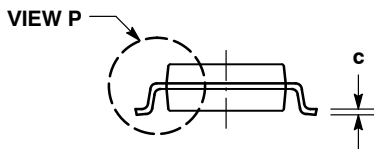
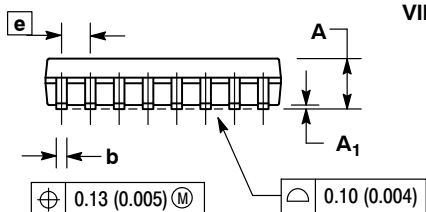
MC74VHC259

PACKAGE DIMENSIONS

SOEIAJ-16
CASE 966-01
ISSUE A



DETAIL P



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| DIM | MILLIMETERS | | INCHES | |
|----------------|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | --- | 2.05 | --- | 0.081 |
| A ₁ | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| c | 0.10 | 0.20 | 0.007 | 0.011 |
| D | 9.90 | 10.50 | 0.390 | 0.413 |
| E | 5.10 | 5.45 | 0.201 | 0.215 |
| e | 1.27 BSC | | 0.050 BSC | |
| H _E | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| L _E | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0° | 10° | 0° | 10° |
| Q ₁ | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | --- | 0.78 | --- | 0.031 |

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